

smitted herewith for filing is the Patent Application of:

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## SHALLOW LOW ENERGY ION IMPLANTATION INTO PAD OXIDE FOR IMPROVING THRESHOLD VOLTAGE

## **STABILITY**

	STABILITY	<u>(</u>		•		7	
Enclosed are:						7510 U.S. PTO 10/828887	
x	3 sheets of drawing(s) - formal.						
x	An assignment of the invention to Chartered Semiconductor Manufacturing Ltd.						
	An associate power of attorney Applicant claims small entity status						
	Request & Certification under 35 USC 122(b)(2)(b)(i)						
The filin	g fee has been	calculated as shown bel	ow:				
		(Col. 1)	(Col. 2)	OTHER THAN	A SMALL ENTITY		
FOR:		NO. FILED	NO. EXTRA	RATE	FEE		
BASIC	FEE	><	>>		<b>\$ 770</b> .		
TOTA	L CLAIMS	16 -20=	0	x 18 =	\$ 0.		
INDEF	CLAIMS	3 -3=	0	x 86 =	\$ 0.		
				SUB TOTAL	\$ 770.		
				ASSIGNMENT	\$40.		
			TOTAL	\$ 810.			
x x	Please charge my Deposit Account No. 19-0033 in the amount of \$810. A duplicate copy of this sheet is enclosed.						
	The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any						
	overnavment	overpayment to Deposit Account No. 19-0033. A duplicate copy of this sheet is enclosed.					
	X Any patent application processing fees under 37 CFR §1.17.						
	Respectfully submitted, STEPPLEN B. ACKERMAN, REG. NO. 37,761						

## **EXPRESS MAIL CERTIFICATE**

## Express Mail No.EV385358770US

I hereby certify that this correspondence is being deposited with the United States Postal Service as Express Mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA, 22313-1450. Applicant and/or Attorney requests the date of deposit as the Filing Date.

Date of deposit